2SK653

GaAs N Channel MES Type

For high-frequency wide-bandwidth low-noise amplification

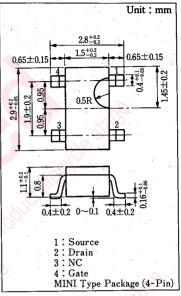
■ Features

- •Wide bandwidth (50-1000MHz)
- •Low noise
- •Low distortion characteristics

■ Absolute Maximum Ratings (Ta=25°C)

Symbol	Value	Unit	
V _{DS}	5	v	
V _{GS}	-4	. V	
ID	50	mA	
I_{G}	1	mA	
P_{D}	200	mW	
T _{ch}	150	°C	
$T_{ m stg}$	$-55 \sim +150$	°C	
	V _{DS} V _{GS} I _D I _G P _D T _{ch}	V _{DS} 5 V _{CS} -4 I _D 50 I _G 1 P _D 200 T _{ch} 150	

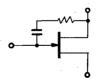
■ Package Dimensions



■ Electrical Characteristics (Ta=25°C)

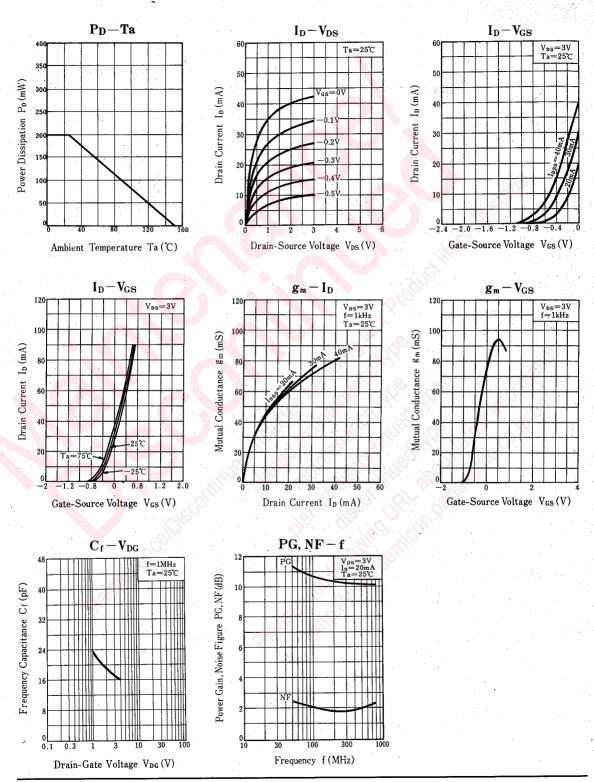
Item	Symbol	Condition	min.	typ.	max.	Unit
Drain Current	I _{DSS} *	$V_{ps} = 3 \text{ V}, V_{gs} = 0$	15	- G	50	mA
Source Current	I _{DSX}	$V_{ps} = 5 \text{ V}, V_{cs} = -3 \text{ V}$	110		50	μA
Gate Cutoff Current	I _{GSS}	$V_{GS}=-3V$, $V_{DS}=0$), , , , , , , , , , , , , , , , , , ,		80	μA
Gate-Source Cutoff Voltage	V _{GSC}	$V_{\rm ps} = 3 \text{ V}, I_{\rm ps} = 0.5 \text{ mA}$	70		-4	V
Mutual Conductance	g _m	$V_{ps} = 3 \text{ V}, I_{ps} = 20 \text{ mA},$	40	75		mS
Power Gain $\begin{array}{c} PG_1 \\ PG_2 \\ PG_3 \end{array}$	PG ₁	V _{DS} =3 V, I _{DS} =20 mA, f=800 MHz	6	8		
	PG ₂	V _{DS} =3 V, I _{DS} =20 mA, f=600 MHz	7	9		dB
	$V_{DS}=3 \text{ V}, I_{DS}=20 \text{ mA}, f=50 \text{ MHz}$	10	13			
Noise Figure NF ₂ NF ₃	$V_{DS} = 3 \text{ V}, I_{DS} = 20 \text{ mA}, f = 800 \text{ MHz}$	-		5		
	$V_{DS}=3 \text{ V}, I_{DS}=20 \text{ mA}, f=600 \text{ MHz}$		2.5	3.2	dB	
	$V_{DS} = 3 \text{ V}, I_{DS} = 20 \text{ mA}, f = 50 \text{ MHz}$		2.7	3.5		

■ Equivalent Circuit



■ Type Name Marking





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